Cam Nguyen

List of Publications by Year in descending order

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| 81 | 814 | 17 h-index | 27 |
|----------|----------------|--------------|----------------|
| papers | citations | | g-index |
| 82 | 82 | 82 | 709 |
| all docs | docs citations | times ranked | citing authors |

| # | Article | IF | CITATIONS |
|----|--|-------|-----------|
| 1 | On the Development of a High-Performance Millimeter-Wave Fully-Integrated BiCMOS FDD T/R Front-End Module for 5G Wireless Systems. IEEE Transactions on Microwave Theory and Techniques, 2022, 70, 2489-2498. | 4.6 | 0 |
| 2 | Dual $\langle i \rangle Q/V \langle i \rangle$ -Band SiGe BiCMOS Low Noise Amplifiers Using Q-Enhanced Metamaterial Transmission Lines. IEEE Transactions on Circuits and Systems II: Express Briefs, 2021, 68, 898-902. | 3.0 | 4 |
| 3 | A High-Isolation 26.5–36.2-GHz T/R Duplexer Module on 0.18-Î⅓m BiCMOS for 5G Systems. IEEE Microwave and Wireless Components Letters, 2021, 31, 300-303. | 3.2 | 3 |
| 4 | Design of CMOS Dual-Band Dual-Function Filter-Switches. Springer Briefs in Electrical and Computer Engineering, 2020, , 45-93. | 0.5 | 0 |
| 5 | 25–53 GHz ultraâ€wideband highâ€isolation passive balanced duplexer on 0.18― <i>μ</i> m BiCMOS fo applications. IET Microwaves, Antennas and Propagation, 2020, 14, 1960-1968. | r 5.Ç | 1 |
| 6 | A V-Band Power Amplifier With Integrated Wilkinson Power Dividers-Combiners and Transformers in 0.18-\$mu\$ m SiGe BiCMOS. IEEE Transactions on Circuits and Systems II: Express Briefs, 2019, 66, 337-341. | 3.0 | 21 |
| 7 | On the investigation of cascode power amplifiers for 5G applications. Microwave and Optical Technology Letters, 2019, 61, 1774-1777. | 1.4 | 3 |
| 8 | A SiGe BiCMOS Concurrent K/V Dual-Band 16-Way Power Divider and Combiner. IEEE Transactions on Circuits and Systems I: Regular Papers, 2018, 65, 1850-1861. | 5.4 | 7 |
| 9 | Design of a Ka/V-Band CMOS T/R Filter-Switch. , 2018, , . | | 1 |
| 10 | A High Power and High Linearity 16.5-25.5 GHz 0.18-ν m BiCMOS Power Amplifier., 2018,,. | | 0 |
| 11 | A K-/Ka-band concurrent dual-band low-noise amplifier employing a feedback notch technique with simultaneous passband gain and stopband rejection control. Microwave and Optical Technology Letters, 2018, 60, 1429-1435. | 1.4 | O |
| 12 | Wideband dual-bandpass 0.18-µm CMOS SPDT switch utilizing dual-band resonator concept. Microwave and Optical Technology Letters, 2018, 60, 1215-1219. | 1.4 | 2 |
| 13 | High-Isolation Multimode Multifunction 24-/60-GHz CMOS Dual-Bandpass Filtering T/R Switch. IEEE Microwave and Wireless Components Letters, 2018, 28, 696-698. | 3.2 | 13 |
| 14 | A \$Kext{-}/Ka\$ -Band Concurrent Dual-Band Single-Ended Input to Differential Output Low-Noise Amplifier Employing a Novel Transformer Feedback Dual-Band Load. IEEE Transactions on Circuits and Systems I: Regular Papers, 2018, 65, 2679-2690. | 5.4 | 32 |
| 15 | Highâ€isolation multiâ€port millimetreâ€wave CMOS dualâ€band T/R switch with integrated bandâ€pass filtering function. IET Microwaves, Antennas and Propagation, 2017, 11, 253-259. | 1.4 | 6 |
| 16 | A Millimeter-Wave CMOS Dual-Bandpass T/R Switch With Dual-Band LC Network. IEEE Microwave and Wireless Components Letters, 2017, 27, 654-656. | 3.2 | 8 |
| 17 | A Wideband Low-Power-Consumption 22–32.5-GHz 0.18- \$mu ext{m}\$ BiCMOS Active Balun-LNA With IM2 Cancellation Using a Transformer-Coupled Cascode-Cascade Topology. IEEE Transactions on Microwave Theory and Techniques, 2017, 65, 536-547. | 4.6 | 19 |
| 18 | Application and implementation of computational electromagnetics in radio-frequency integrated-circuit design., 2017,,. | | 0 |

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| 19 | On the development of a dual-band 0.18-pm BiCMOS transmit/receive switch for microwave and millimeter-wave array transceivers. , 2017, , . | | 0 |
| 20 | Investigation of an advanced millimeter-wave 94-GHz phased array for communications and sensing. , 2016, , . | | 0 |
| 21 | A High-Gain Power-Efficient Wideband V-Band LNA in 0.18- SiGe BiCMOS. IEEE Microwave and Wireless Components Letters, 2016, 26, 276-278. | 3.2 | 25 |
| 22 | Ultra-Wideband Active Balun Topology and Its Implementation on SiGe BiCMOS Across DC-50 GHz. IEEE Microwave and Wireless Components Letters, 2016, 26, 720-722. | 3.2 | 12 |
| 23 | Some recent developments of millimeter-wave RFIC attenuators. , 2016, , . | | 0 |
| 24 | On the design of CMOS phase shifters with small insertionâ€loss variation for phased arrays and its validation at 24 GHz. Microwave and Optical Technology Letters, 2016, 58, 2203-2210. | 1.4 | 0 |
| 25 | A 4.6–5.9 GHz fully integrated 0.25-Âμm CMOS complementary LC VCO with buffer. , 2016, , . | | 1 |
| 26 | A Novel Concurrent 22–29/57–64-GHz Dual-Band CMOS Step Attenuator With Low Phase Variations. IEEE Transactions on Microwave Theory and Techniques, 2016, 64, 1867-1875. | 4.6 | 26 |
| 27 | Concurrent Dual -Band T/R/Calibration Switch Module With Quasi-Elliptic Dual-Bandpass Frequency Response Implementing Metamaterial Transmission Line and Negative Resistance. IEEE Transactions on Microwave Theory and Techniques, 2016, 64, 585-598. | 4.6 | 11 |
| 28 | Design of a novel DC-67-GHz 0.18-μm SiGe BiCMOS power divider. , 2015, , . | | 1 |
| 29 | A small-insertion-loss-variation phase shifter with optimized body-floating transistors. , 2015, , . | | 3 |
| 30 | Design of 60-GHz 0.18-μm SiGe BiCMOS OOK modulator for Gbps DATA communication. , 2015, , . | | 0 |
| 31 | A 60 GHz 2.5 Gbps OOK Modulator with Data-Dependent Impedance Cell for Enhanced ON/OFF Isolation in 0.18 <formula formulatype="inline"><tex notation="TeX">\$mu\$</tex> </formula> m BiCMOS Process. IEEE Microwave and Wireless Components Letters, 2015, 25, 244-246. | 3.2 | 7 |
| 32 | A new impedance-matching technique for dual-band RF circuits and antennas., 2015,,. | | 3 |
| 33 | An Ultra-Wideband Low-Loss Millimeter-Wave Slow-Wave Wilkinson Power Divider on 0.18 & lt;formula formulatype="inline"> <tex notation="TeX">\$mu{m m}\$</tex> SiGe BiCMOS Process. IEEE Microwave and Wireless Components Letters. 2015, 25, 331-333. | 3.2 | 36 |
| 34 | A 44 GHz CMOS RFIC Dual-Function Attenuator with Band-Pass-Filter Response. IEEE Microwave and Wireless Components Letters, 2015, 25, 241-243. | 3.2 | 29 |
| 35 | Multi-band radio-frequency integrated circuits for multiband and multimode wireless communication, radar and sensing systems in harsh environments. , 2014, , . | | 3 |
| 36 | A 10.5-GHz divide-by-3 injection-locked frequency divider with enhanced locking range by even-harmonic phase tuning in 0.18 $\hat{1}$ /4m BiCMOS. Microwave and Optical Technology Letters, 2014, 56, 2249-2252. | 1.4 | 1 |

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| 37 | K/Ka-band Single-Pole Single-Throw switch with integrated filtering function. , 2014, , . | | 2 |
| 38 | A Concurrent \$Ku/K/Ka\$ Tri-Band Distributed Power Amplifier With Negative-Resistance Active Notch Using SiGe BiCMOS Process. IEEE Transactions on Microwave Theory and Techniques, 2014, 62, 125-136. | 4.6 | 22 |
| 39 | DCâ€toâ€67 GHz highâ€speed BiCMOS BJT characterization with onâ€wafer calibration and EMâ€based deâ€embedding. Microwave and Optical Technology Letters, 2014, 56, 1285-1292. | 1.4 | 2 |
| 40 | A 16.5–28 GHz 0.18-\$mu\$m BiCMOS Power Amplifier With Flat \$19.4 pm 1.2\$ dBm Output Power. IEEE Microwave and Wireless Components Letters, 2014, 24, 108-110. | 3.2 | 24 |
| 41 | Dual-band filter design with new frequency-transformation method having both band-pass and high-pass responses. , $2014, , .$ | | 2 |
| 42 | New Technique for Synthesizing Concurrent Dual-Band Impedance-Matching Filtering Networks and ${\theta }_{0.18-}\$ mu{hbox {m}}\$ SiGe BiCMOS 25.5/37-GHz Concurrent Dual-Band Power Amplifier. IEEE Transactions on Microwave Theory and Techniques, 2013, 61, 3927-3939. | 4.6 | 30 |
| 43 | A Concurrent Tri-Band Low-Noise Amplifier With a Novel Tri-Band Load Resonator Employing Feedback Notches. IEEE Transactions on Microwave Theory and Techniques, 2013, 61, 4195-4208. | 4.6 | 28 |
| 44 | A 10& \pm x2013; 67-GHz CMOS step attenuator with improved flatness and large attenuation range. , 2013, , . | | 3 |
| 45 | A 13/24/35-GHz concurrent tri-band LNA with feedback notches. , 2013, , . | | 4 |
| 46 | A 10–67-GHz CMOS Dual-Function Switching Attenuator With Improved Flatness and Large Attenuation Range. IEEE Transactions on Microwave Theory and Techniques, 2013, 61, 4118-4129. | 4.6 | 50 |
| 47 | A BiCMOS Kaâ€band RFâ€pulse former for shortâ€range highâ€resolution radar and highâ€dataâ€rate communication systems. Microwave and Optical Technology Letters, 2013, 55, 2773-2777. | 1.4 | 0 |
| 48 | UWB CMOS transmitters for UWB communications. , 2013, , . | | 0 |
| 49 | A concurrent dual-band low-noise amplifier for K- and Ka-band applications in SiGe BiCMOS technology. , $2013,$, . | | 12 |
| 50 | Dual-injection-locked & Dual-i | | 1 |
| 51 | Low-cost integrated-circuit transmitter and receiver for UWB communications. , 2013, , . | | 1 |
| 52 | New dual-band band-pass filter design with enhanced dual-band skirt characteristics. , $2013, \ldots$ | | 2 |
| 53 | Investigation of on-chip phase-noise reduction using self-injection technique on fully integrated frequency dividers. , 2012, , . | | 1 |
| 54 | Low-Power-Consumption Wide-Locking-Range Dual-Injection-Locked 1/2 Divider Through Simultaneous Optimization of VCO Loaded \$Q\$ and Current. IEEE Transactions on Microwave Theory and Techniques, 2012, 60, 3161-3168. | 4.6 | 15 |

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| 55 | A multistandard dual-mode fully-integrated miniature, low-power-consumption 860-960 MHz CMOS RFID reader for mobile communications, sensing, and networking. Microwave and Optical Technology Letters, 2012, 54, 2487-2491. | 1.4 | 1 |
| 56 | A complete single-chip multi-standard dual-mode CMOS RFID reader with low power consumption. , 2012, , . | | 2 |
| 57 | New Ultra-High-Isolation RF Switch Architecture and Its Use for a 10–38-GHz 0.18-\$mu\$m BiCMOS Ultra-Wideband Switch. IEEE Transactions on Microwave Theory and Techniques, 2011, 59, 345-353. | 4.6 | 33 |
| 58 | Fully integrated CMOS impulse UWB transmitter front-ends with BPSK modulation. Microwave and Optical Technology Letters, 2010, 52, 1609-1614. | 1.4 | 3 |
| 59 | Tunable monocycle pulse generator using switch controlled delay line and tunable RC network for UWB systems. , 2010, , . | | 5 |
| 60 | An extremely miniaturized 15-GHz CMOS distributed voltage-controlled oscillator. Microwave and Optical Technology Letters, 2009, 51, 1953-1955. | 1.4 | 2 |
| 61 | A CMOS fully integrated concurrent dual ultrawideband receiver frontend. Microwave and Optical Technology Letters, 2009, 51, 2003-2007. | 1.4 | 1 |
| 62 | Integrated CMOS impulse UWB receiver frontâ€end design. Microwave and Optical Technology Letters, 2009, 51, 2590-2595. | 1.4 | 1 |
| 63 | Integrated Multilayered On-Chip Inductors for Compact CMOS RFICs and Their Use in a Miniature Distributed Low-Noise-Amplifier Design for Ultra-Wideband Applications. IEEE Transactions on Microwave Theory and Techniques, 2008, 56, 1783-1789. | 4.6 | 16 |
| 64 | An Ultra-Wideband Low Power-Consumption Low Noise-Figure High-Gain RF Power-Efficient DC–3.5-GHz CMOS Integrated Sampling Mixer Subsystem. IEEE Transactions on Microwave Theory and Techniques, 2008, 56, 1069-1075. | 4.6 | 10 |
| 65 | Microstrip quasi-horn antenna for UWB radars and sensors. , 2008, , . | | 0 |
| 66 | High power and linearity CMOS RFIC transmit-receive switch for ultra-Wideband radar and communication systems. , 2008, , . | | 0 |
| 67 | Theoretical investigation of a novel location sensor. , 2008, , . | | 1 |
| 68 | An ultra-Wideband uniplanar antenna for UWB systems. , 2008, , . | | 0 |
| 69 | A New CMOS Multilayer Electromagnetic Band-Gap Microstrip Line and Experimental Investigation of UWB Pulse Propagation. IEEE Microwave and Wireless Components Letters, 2007, 17, 522-524. | 3.2 | 1 |
| 70 | A multi-band UWB radar for sensing objects. , 2007, , . | | 1 |
| 71 | A Ka-band stepped-frequency radar sensor for surface and subsurface sensing. , 2007, , . | | 0 |
| 72 | Development of a Tunable Multiband UWB Radar Sensor and Its Applications to Subsurface Sensing. IEEE Sensors Journal, 2007, 7, 51-58. | 4.7 | 59 |

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| 73 | A power-efficient CMOS UWB signal-generation module. , 2007, , . | | O |
| 74 | An integrated CMOS transmitter-antenna for UWB systems. , 2007, , . | | 0 |
| 75 | Ultra-Compact High-Linearity High-Power Fully Integrated DC–20-GHz 0.18-\$mu{hbox {m}}\$ CMOS T/R Switch. IEEE Transactions on Microwave Theory and Techniques, 2007, 55, 30-36. | 4.6 | 117 |
| 76 | A Novel Multilayer Aperture-Coupled Cavity Resonator for Millimeter-Wave CMOS RFICs. IEEE Transactions on Microwave Theory and Techniques, 2007, 55, 783-787. | 4.6 | 28 |
| 77 | Multilayer Design Techniques for Extremely Miniaturized CMOS Microwave and Millimeter-Wave Distributed Passive Circuits. IEEE Transactions on Microwave Theory and Techniques, 2006, 54, 4218-4224. | 4.6 | 48 |
| 78 | Development of a low-cost, compact planar synchronous receiver for UWB systems., 2006,,. | | 3 |
| 79 | Some Recent Developments of Microwave and Millimeter-wave Sensors. Sensing and Imaging, 2006, 7, 47-70. | 1.5 | 3 |
| 80 | A multipulse transmitter for UWB radar and communication systems. , 2006, , . | | 2 |
| 81 | Announcement of Journal Changes. Subsurface Sensing Technologies and Applications, 2005, 6, 291-291. | 0.9 | 0 |